Technical Data Sheet

Features

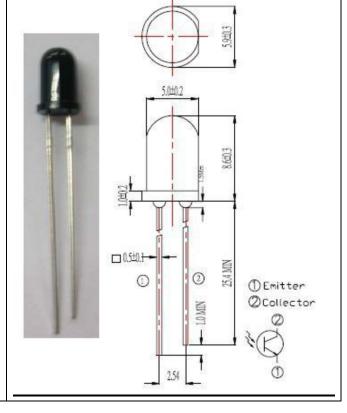
- Fast response tine
- High photo sensitivity
- Pb free
- This product itself will remain within RoHS conpliant version.

Descriptions

• YG1006 is a high speed and high sensitive NPNsiicon phototransistor in a standard5mm package.

Due to its black epoxy the device is sensitive to infrared radiation.

Package Dimensions



Note: 1. All dimensions are in millimeters

2. Tolerances unless dimensions ± 0.25 mm

Absoulute Maximum Ratings ($Ta=25^{\circ}$)

Parameter	Symbol	rating	units	
Collector-Emitter Voltage	Vceo	30	V	
Emitter-Collector-Voltage	Veco	5	V	
Collector Current	Ic	20	mA	
Operating Temperature	Topr	-25~+85℃	$^{\circ}$	
Storage Temperature	Tstg	-40+85℃	$^{\circ}$	
Lead Soldering Temperature	Tsol	260	\mathbb{C}	
Power Dissipation at (or	Рс	75	mW	
below) 25℃ FreeAir				
Temperature				

Electro-Opticai Characteristcs (Ta=25°C)

Rankings

Param	eter	Sym	bol	Condition		Min. Typ.		Max.	Units	
Collector- Breakdown		BVCEO		Ic=100µA Ee=0mW/C m²		30				V
Emitter-C Saturation		BVeco		IE=100µA Ee=0mW/C m²		5				V
Collector-Emitter Saturation Voltage		VCE	(sat)	Ic=2mA Ee=1mW/C m ²					0.4	V
Rise T	Time t			VCE=5V			15			μS
Fall Time		tf		Ic=1mA RL=1000Ω			15			
Collector		ICEO		$\begin{array}{c} \text{Ee=0mW/C} \ \text{m}^{\text{a}} \\ \text{Vce=20V} \end{array}$					100	nA
On State Collector Current		Ic(o	on)	Ee=1mW/C m² VCE=5V		1.77			7.07	mA
Wavelength Sensiti							940			nm
Rang of Spectral Bandwidth λ0.5			760-1		760-11	.00		nm		
Parameter	Symbol	Min	Max	Unit	Test Condi	tion				
					Vce	=5V				
J	Ic(on)	1.77	3.61	mA	Ee=1n	nW/C m²				
K		2.67	5.07							
L		4.18	7.07							

Typical Electro-Optical Characteristics Curves

Fig.1Collector Power Dissipation vs.

Ambient Temperature

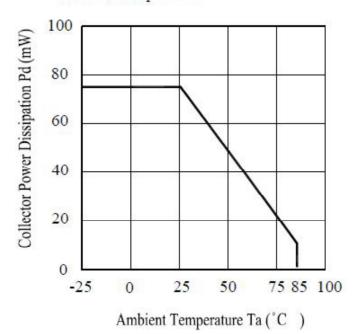


Fig.2 Spectral Sensitivity

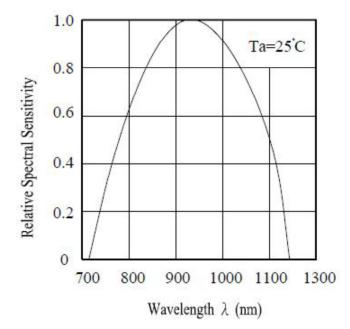


Fig.3 Relative Collector Current vs.

Ambient Temperature

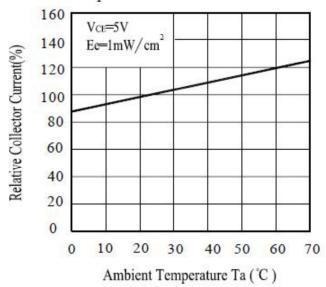
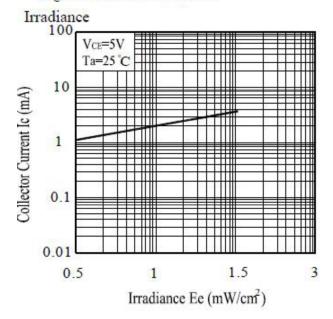


Fig.4 Collector Current vs.



Typical Electro-Optical Characteristecs

Fig.5 Collector Dark Current vs. Ambient Temperature

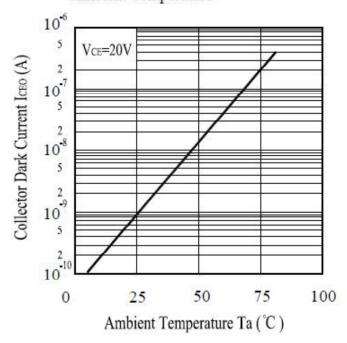
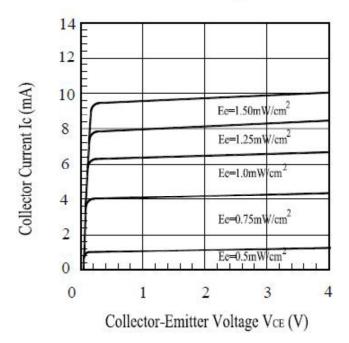


Fig.6 Collector Current vs.

Collector-Emitter Voltage



Product Page http://www.sunrom.com/m/5533

Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP. : 260°C±5°C	10secs	22pcs		0/1
2	Temperature Cycle	H:+100°C ↑ 15mins L:-40°C ↑ 5mins 15mins	300Cycles	22pes	$I_{C(ON)} \le L \times 0.8$	0/1
3	Thermal Shock	H:+100°C	300Cycles	22pes	L: the initial test value	0/1
4	High Temperature Storage	TEMP. : +100℃	1000hrs	22pes		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000hrs	22pes		0/1
6	DC Operating Life	V _{CE} =5V	1000hrs	22pes		0/1
7	High Temperature/ High Humidity	85℃ / 85% R.H	1000hrs	22pcs		0/1